COMPLEMENTARY SILICON POWER TRANSISTORS

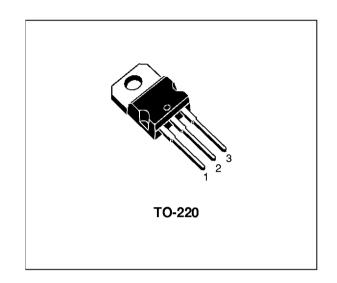
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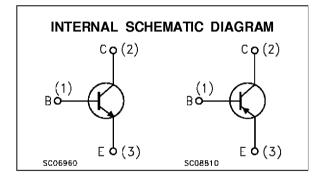
DESCRIPTION

The BD241A, BD241B and BD241C are silicon epitaxial-base NPN transistors mounted in Jedec TO-220 plastic package.

They are inteded for use in medium power linear and switching applications.

The complementary PNP types are BD242A, BD242B and BD242C respectively.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Value		Unit
		NPN	BD241A	BD241B	BD241C	
		PNP	BD242A	BD242B	BD242C]
V _{CER}	Collector-Base Voltage ($R_{BE} = 100 \Omega$)		70	90	115	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)		60	80	100	V
V _{EBO}	Emitter-Base Voltage (I _C = 0)			5		V
Ic	Collector Current			3		Α
I _{CM}	Collector Peak Current			5		Α
I _B	Base Current			1		Α
P _{tot}	Total Dissipation at T _c ≤ 25 °C			40		W
P _{tot}	Total Dissipation at T _{amb} ≤ 25 °C			2		W
T _{stg}	Storage Temperature			-65 to 150		°C
Tj	Max. Operating Junction Temperature			150		°C

For PNP types voltage and current values are negative.

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THERMAL DATA

	R _{thj-case}	Thermal	Resistance	Junction-case	Max	3.13	°C/W
١	R _{thj-amb}	Thermal	Resistance	Junction-ambient	Max	62.5	°C/W

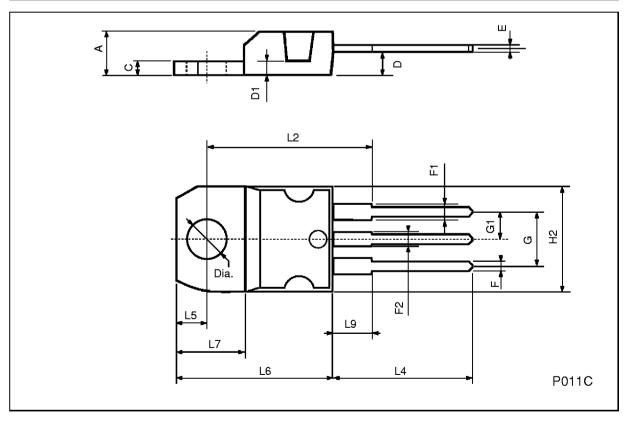
ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = rated V _{CEO}			0.2	m A
I _{CEO}	Collector Cut-off Current (I _B = 0)	for BD241A/BD242A			0.3 0.3 0.3	mA mA mA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V			1	m A
V _{CEO(sus)} *	Collector-Emitter Sustaining Voltage	I _C = 30 mA for BD241A/BD242A for BD241B/BD242B for BD241C/BD242C	60 80 100			<<<
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	Ic = 3 A I _B = 0.6 A			1.2	V
V _{BE} *	Base-Emitter Voltage	Ic = 3 A VcE = 4 V			1.8	\ \
h _{FE} *	DC Current Gain	Ic = 1 A	25 10			
h _{fe}	Small Signal Current Gain	I _C = 0.5 A V _{CE} = 10 V f = 1MHz I _C = 0.5 A V _{CE} = 10 V f = 1KHz	3 20			

* Pulsed: Pulse duration = 300 μs, duty cycle ≤ 2 % For PNP types voltage and current values are negative.

TO-220 MECHANICAL DATA

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α	4.40		4.60	0.173		0.181	
С	1.23		1.32	0.048		0.051	
D	2.40		2.72	0.094		0.107	
D1		1.27			0.050		
Е	0.49		0.70	0.019		0.027	
F	0.61		0.88	0.024		0.034	
F1	1.14		1.70	0.044		0.067	
F2	1.14		1.70	0.044		0.067	
G	4.95		5.15	0.194		0.203	
G1	2.4		2.7	0.094		0.106	
H2	10.0		10.40	0.393		0.409	
L2		16.4			0.645		
L4	13.0		14.0	0.511		0.551	
L5	2.65		2.95	0.104		0.116	
L6	15.25		15.75	0.600		0.620	
L7	6.2		6.6	0.244		0.260	
L9	3.5		3.93	0.137		0.154	
DIA.	3.75		3.85	0.147		0.151	



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